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Application of : Takashi TAKAHASHI

Dkt. 2271/60102

Serial No. : 09/408,437

Date Filed : September 29, 1999

For : SEMICONDUCTOR DEVICE WITH SATURABLE ABSORBING
LAYER

Group Art Unit: 2828

Examiner: A. Rodriguez

Assistant Commissioner for Patents
Washington, D.C. 20231

1185 Avenue of the Americas
New York, N.Y. 10036

Sir:

AMENDMENT

In response to the Office Action dated March 28, 2002, please amend the above-identified application as follows:

In the Claims:

Please amend claims 1, 6, 13 and 18 as follows:

- Sub 07
1. (Amended) A semiconductor device comprising:
a semiconductor substrate of a first conductivity type;
a first cladding layer of said first conductivity type formed on said semiconductor substrate;
- AI

TECHNOLOGY CENTER 2800

JUL - 8 2002

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